

REMARKS

Claims 1-24 are pending. Claim 21 is herein amended, no other amendments are made. Applicants submit that the amendments do not add new material to the current Application. Support for the amendment can be found on at least page 4, line 2 and page 10, lines 9-10. No amendment made is related to the statutory requirements of patentability unless expressly stated herein. No amendment made is for the purpose of narrowing the scope of any claims, unless Applicants argue herein that such amendment is made to distinguish over a particular reference or combination of references.

Claims 1-20 were allowed and claims 23-24 were objected to because they depend from rejected claim 21. Only claims 21-22 were rejected.

Claims RejectionsClaims 21-22 are patentable under 35 U.S.C. 103(e) over Deleonibus in view of Bhandari

Applicants respectfully submit claims 21-22 are patentable under 35 U.S. 103(a) over Deleonibus (US 6,091,076) in view of Bhandari (U.S. 6,379,748) because the combination fails to teach or suggest all features of independent claim 21, from which claim 22 depends. More specifically, Deleonibus in view of Bhandari fails to teach or suggest epitaxially growing from the channel structure a current electrode, as stated in (amended) claim 21. As the Examiner corrected states Deleonibus fails to teach epitaxially growing a current electrode and the Examiner relies upon Bhandari to teach this feature. Assuming arguendo that Bhandari motivates one skilled in the art to form Deleonibus's current electrodes by epitaxial growth, Deleonibus cannot epitaxially growing from the channel structure a current electrode because Deleonibus's channel structure is isolated by isolation regions 88 and 90. (See Fig. 8.) At least for this reason Deleonibus in view of Bhandari fails to teach or suggest epitaxially growing from the channel structure a current electrode, and claims 21-22 are patentable over Deleonibus in view of Bhandair under 35 U.S.C. 103(a).

Applicants thank the Examiner for pointing out allowable subject matter. Believing to have responded to every issue raised by the Examiner in the last communication mailed, Applicants believe the present Application is currently in a condition of allowance. Applicants

earnestly solicit allowance of all pending claims. Please contact Applicant's practitioner listed below if there are any issues.

If Applicant has overlooked any additional fees, or if any overpayment has been made, the Commissioner is hereby authorized to credit or debit Deposit Account 503079, Freescale Semiconductor, Inc.

Respectfully submitted,

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